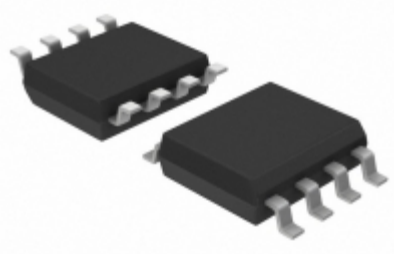


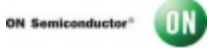


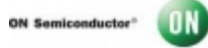




	NTMD6N04R2G	
	Hersteller-Teilenummer:	NTMD6N04R2G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET 2N-CH 40V 4.6A 8SOIC
	Datenblätter:	 NTMD6N04R2G.pdf
	RoHs Status:	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	Lagerzustand:	New original, 41934 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	NTMD6N04R2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 40V 4.6A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	41934 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.29W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.6A
Rds On (Max) @ Id, Vgs	34 mOhm @ 5.8A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	900pF @ 32V
Verpackung	Tape & Reel (TR)





































NTMD6N04R2G ist neu im Original, Suche NTMD6N04R2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMD6N04R2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMD6N04R2G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMD6N03 AMI Semiconductor / ON Semiconductor NTMD6N03 ON</p>	 <p>NTMD6P02R2 ON NTMD6P02R2 ON</p>	 <p>NTMD6N03DR2G ON NTMD6N03DR2G ON</p>	 <p>NTMD6N04 AMI Semiconductor / ON Semiconductor NTMD6N04 ON</p>
 <p>NTMD6P02R2G AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 4.8A 8SOIC</p>	 <p>NTMD6N03R2G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 6A 8SOIC</p>	 <p>NTMD6P02R2SG AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 20V 4.8A 8SOIC</p>	 <p>NTMD6N03R2 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 6A 8SOIC</p>

heiße Teile

Mehr

 NTMD3P03	 NTMD3P03R2	 NTMD3P03R2G	 NTMD4102PR2G	 NTMD4184PF
 NTMD4184PFR2G	 NTMD4820N	 NTMD4820NR2G	 NTMD4840N	 NTMD4840NR2G
 NTMD4884NFR2G	 NTMD4N03	 NTMD4N03R2G	 NTMD5836NL	 NTMD5836NLR2G
 NTMD5838NL	 NTMD5838NLR2G	 NTMD6N02	 NTMD6N02DR2G	 NTMD6N02R2G
 NTMD6N03	 NTMD6N03DR2G	 NTMD6N03R2	 NTMD6N03R2G	 NTMD6N04
 NTMD6P02	 NTMD6P02R2	 NTMD6P02R2G	 NTMD6P02R2G.	 NTMD6P02R2SG
 NTMFD4901NF1G	 NTMFD4901NFT1G	 NTMFD4902NF1G	 NTMFD4902NFT1G	 NTMFD4C85NT1G
 NTMFD4C85NTG	 NTMFD4H089NFT1G	 NTMFS4108NT1G	 NTMFS4108NT3G	 NTMFS4119NT3G
 NTMFS4120NT1G	 NTMFS4121NT1G	 NTMFS4701NT1G	 NTMFS4707NT1G	 NTMFS4708NT1G
 NTMFS4709NT1G	 NTMFS4709NT3G	 NTMFS4744NT1G	 NTMFS4821NT1G	 NTMFS4823NT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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